

SHINDENGEN

HVX-2 Series Power MOSFET

N-Channel Enhancement type

**2SK2670
(F5S90HVX2)**

900V 5A

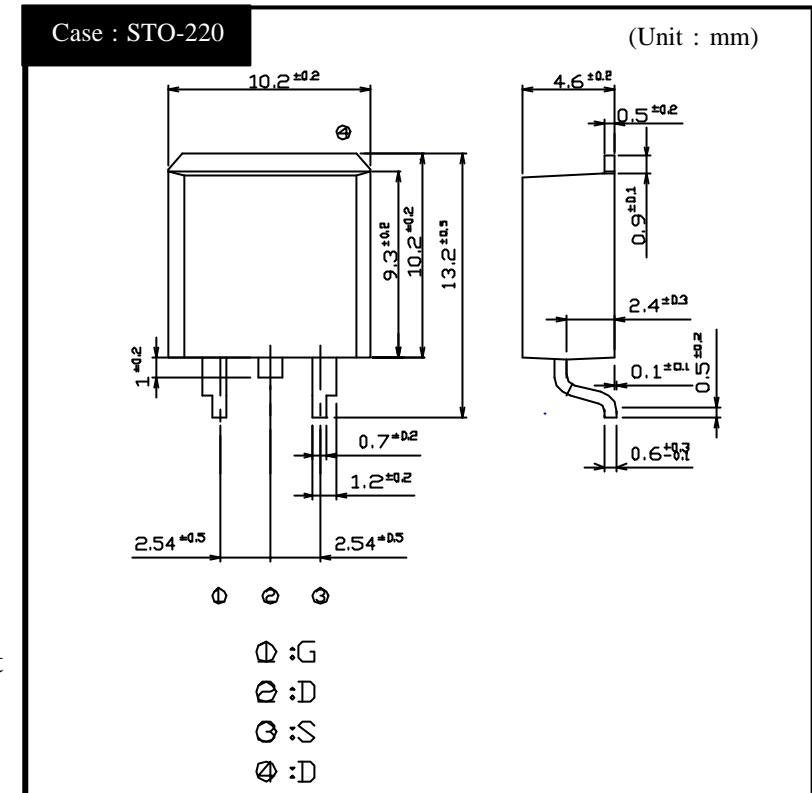
FEATURES

Input capacitance (C_{iss}) is small.
Especially, input capacitance at 0 bias is small.
The static $R_{ds(on)}$ is small.
The switching time is fast.
Avalanche resistance guaranteed.

APPLICATION

Switching power supply of AC 240V input
High voltage power supply
Inverter

OUTLINE DIMENSIONS



RATINGS

Absolute Maximum Ratings (T_c = 25 °C)

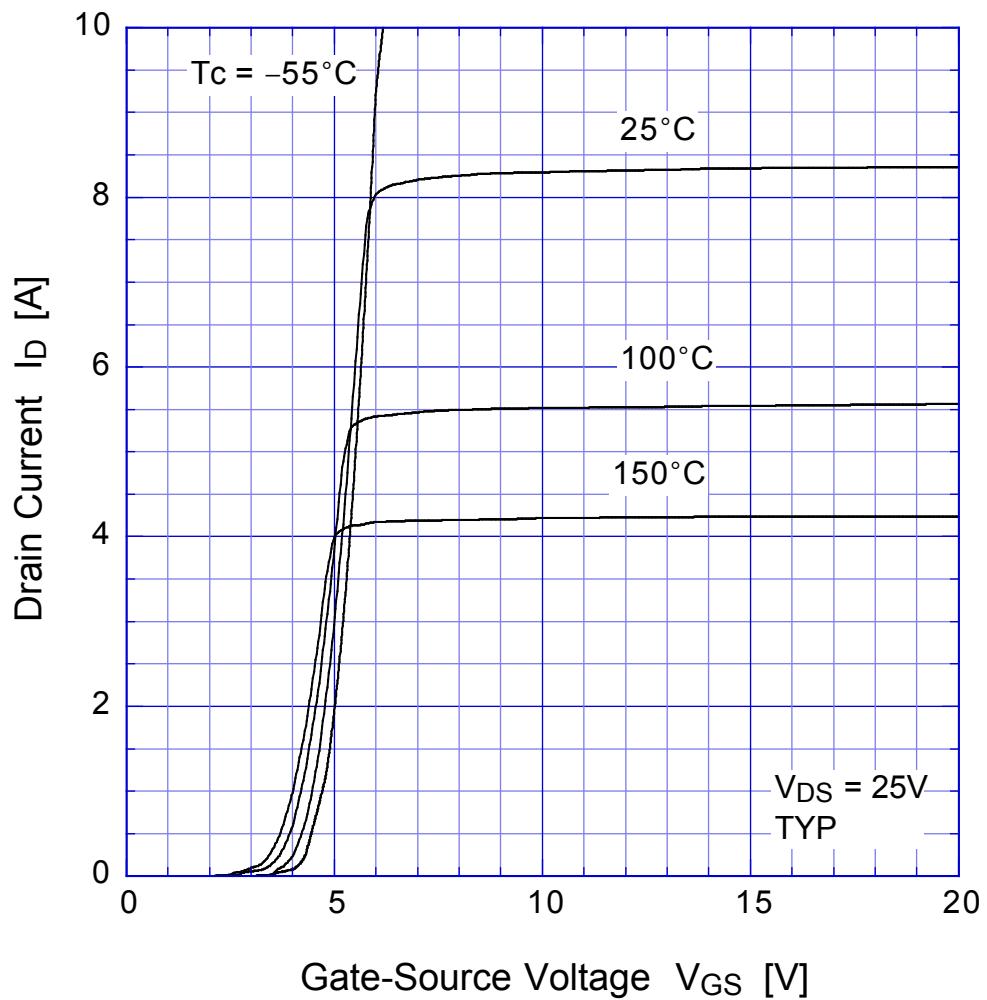
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T _{stg}		-55 ~ 150	
Channel Temperature	T _{ch}		150	
Drain-Source Voltage	V _{DSS}		900	V
Gate-Source Voltage	V _{GSS}		± 30	
Continuous Drain Current (DC)	I _D		5	
Continuous Drain Current (Peak)	I _{DP}	Pulse width 10 μs, Duty cycle 1/100	10	A
Continuous Source Current (DC)	I _S		5	
Total Power Dissipation	P _T		60	W
Repetitive Avalanche Current	I _{AR}	T _{ch} = 150	5	A
Single Avalanche Energy	E _{AS}	T _{ch} = 25	100	mJ
Repetitive Avalanche Energy	E _{AR}	T _{ch} = 25	10	

●Electrical Characteristics T_c = 25°C

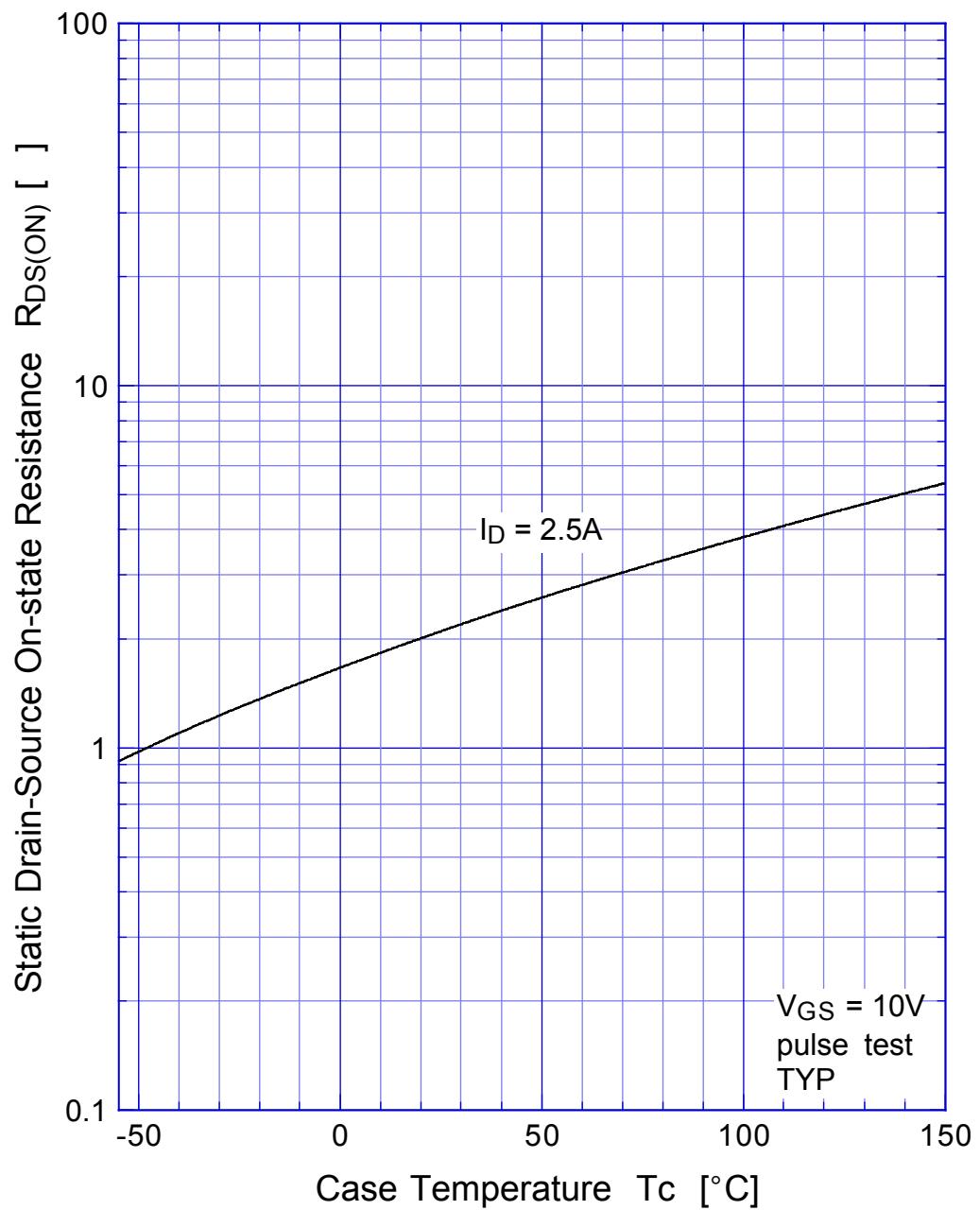
Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	V _{(BR)DSS}	ID = 1mA, V _{GS} = 0V	900			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 900V, V _{GS} = 0V			250	μ A
Gate-Source Leakage Current	I _{GSS}	V _{GS} = ±30V, V _{DS} = 0V			±0.1	
Forward Transconductance	g _f s	ID = 2.5A, V _{DS} = 10V	2.4	4.0		S
Static Drain-Source On-state Resistance	R _{D(S)ON}	ID = 2.5A, V _{GS} = 10V		2.1	2.8	Ω
Gate Threshold Voltage	V _{TH}	ID = 1mA, V _{DS} = 10V	2.5	3.0	3.5	V
Source-Drain Diode Forward Voltage	V _{SD}	I _S = 2.5A, V _{GS} = 0V			1.5	
Thermal Resistance	θ _{jc}	junction to case			2.08	°C/W
Total Gate Charge	Q _g	V _{DD} = 400V, V _{GS} = 10V, I _D = 5A		45		nC
Input Capacitance	C _{iss}	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz		1140		pF
Reverse Transfer Capacitance	C _{rss}			23		
Output Capacitance	C _{oss}			105		
Turn-On Time	t _{on}	ID = 2.5A, V _{GS} = 10V, R _L = 60Ω		55	100	ns
Turn-Off Time	t _{off}			210	350	

2SK2670

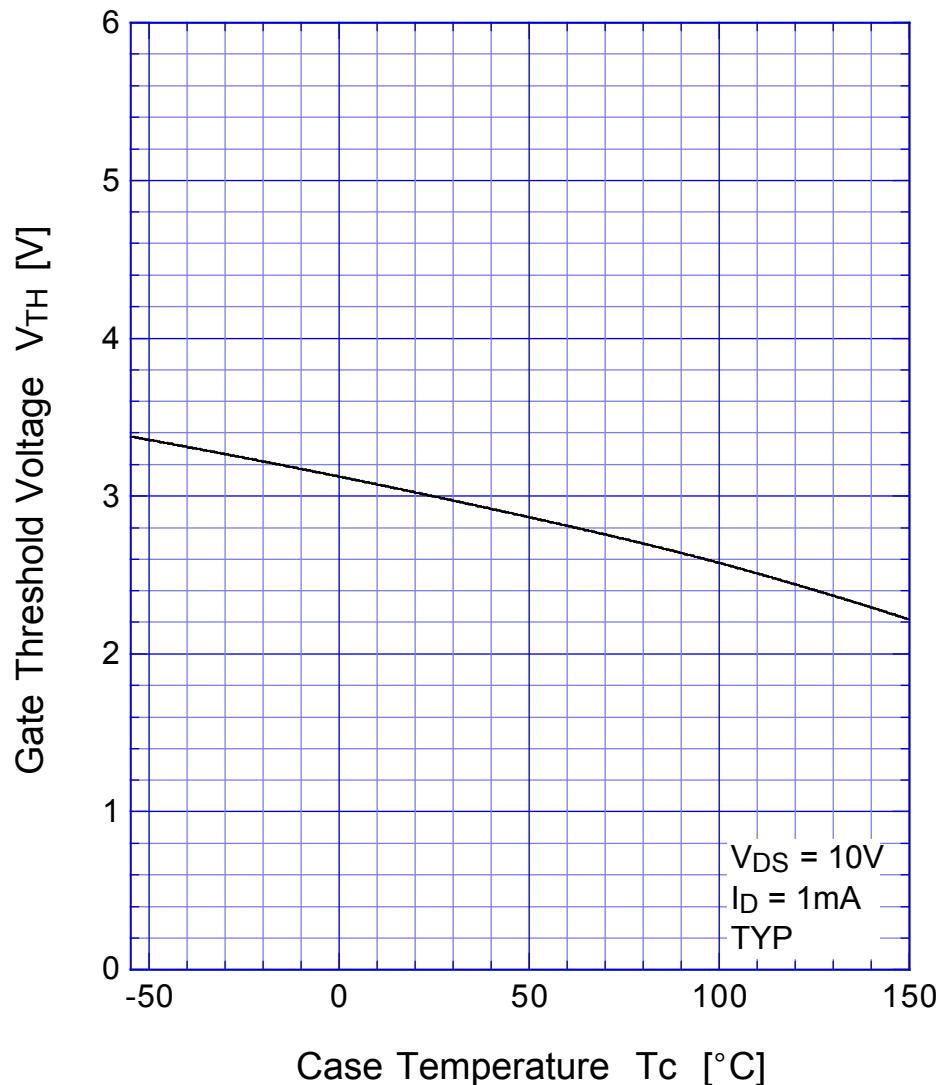
Transfer Characteristics



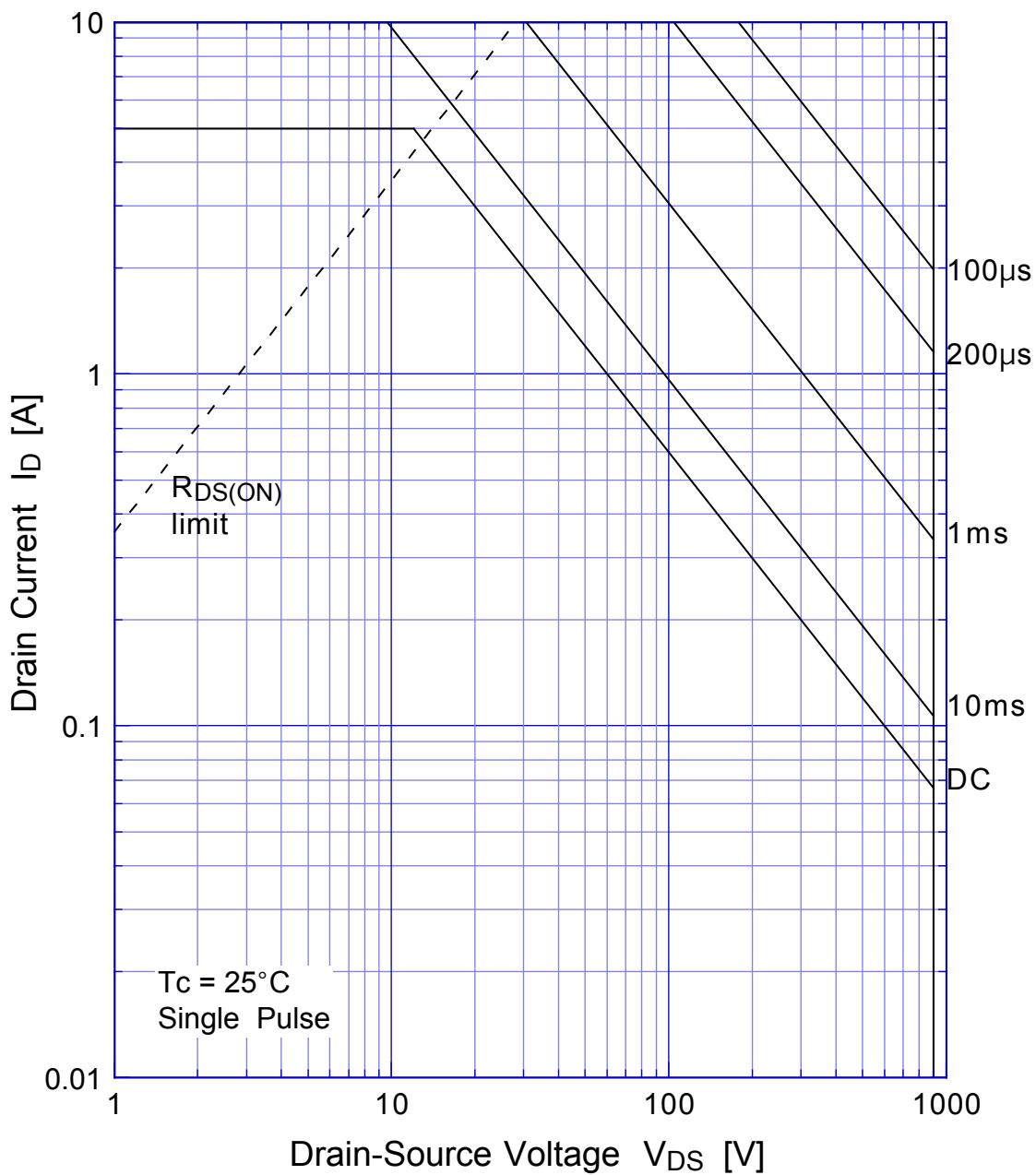
2SK2670 Static Drain-Source On-state Resistance



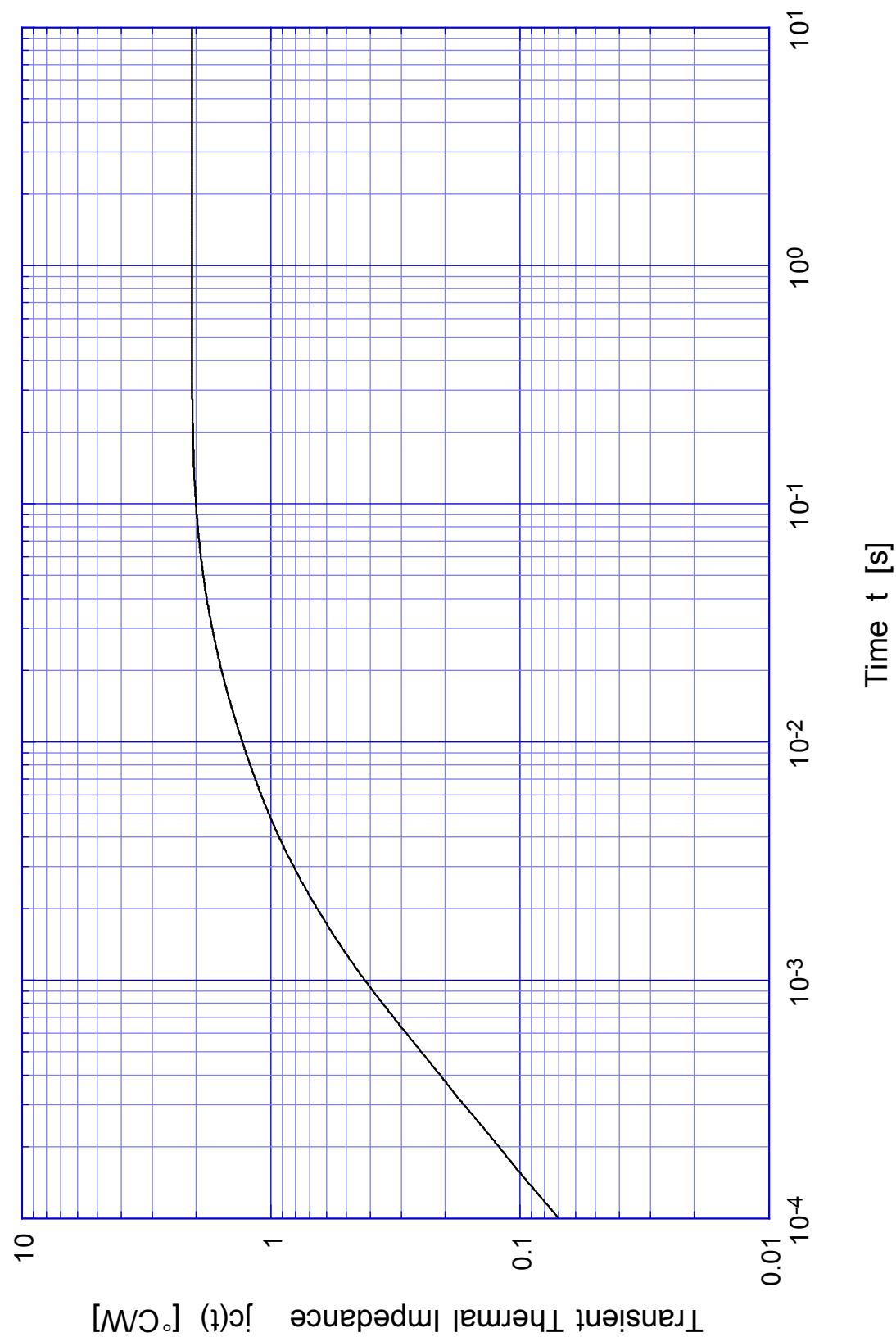
2SK2670 Gate Threshold Voltage



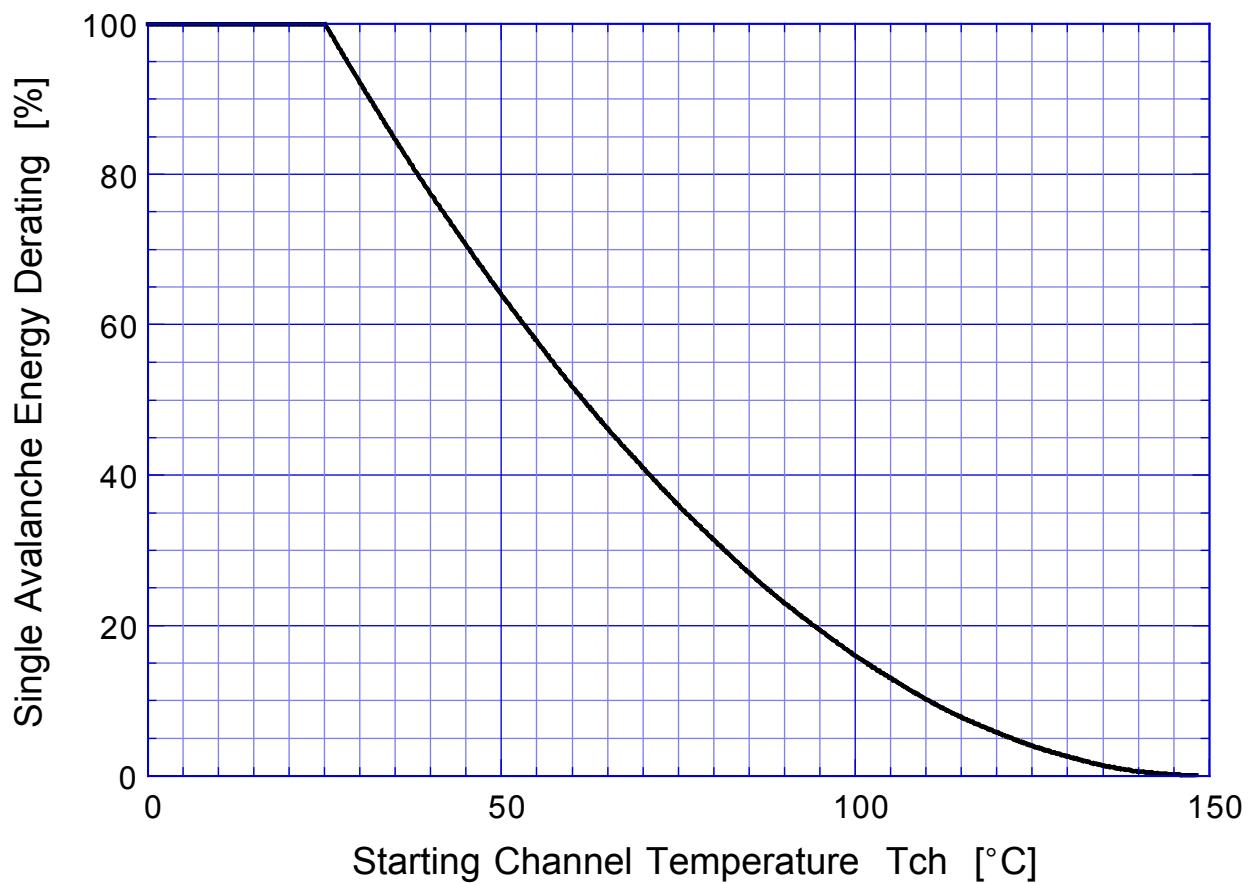
2SK2670 Safe Operating Area



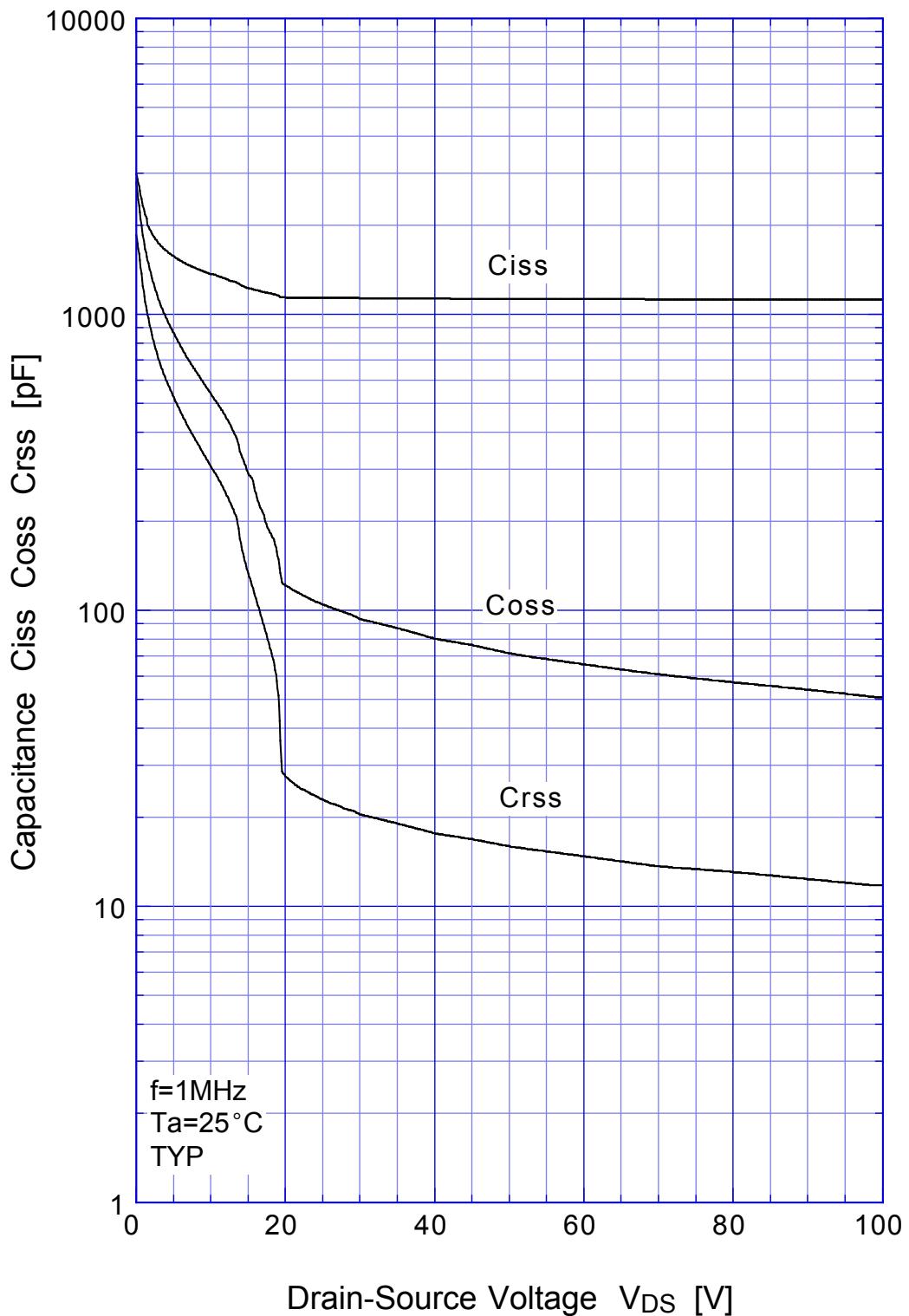
2SK2670 Transient Thermal Impedance



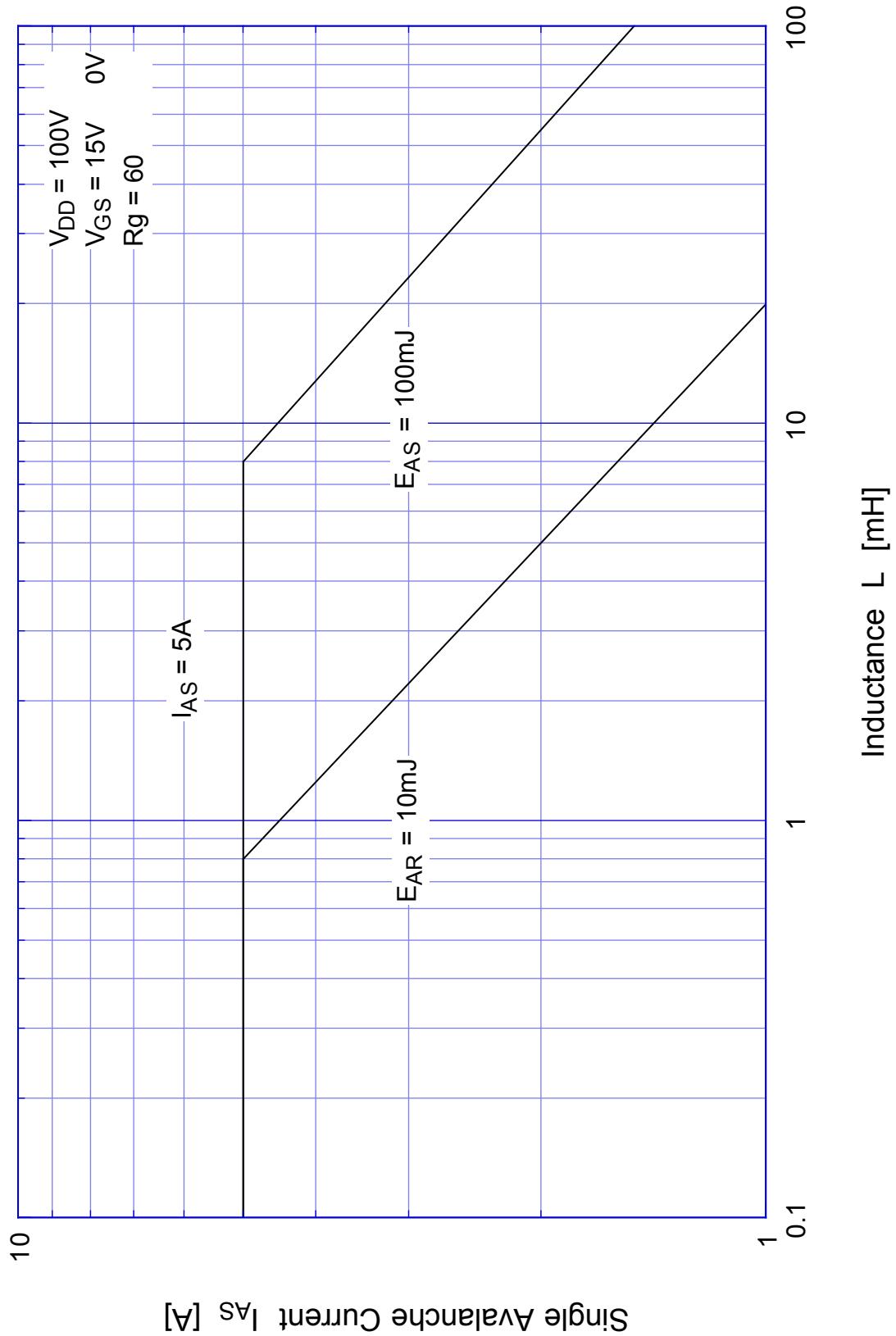
2SK2670 Single Avalanche Energy Derating



2SK2670 Capacitance

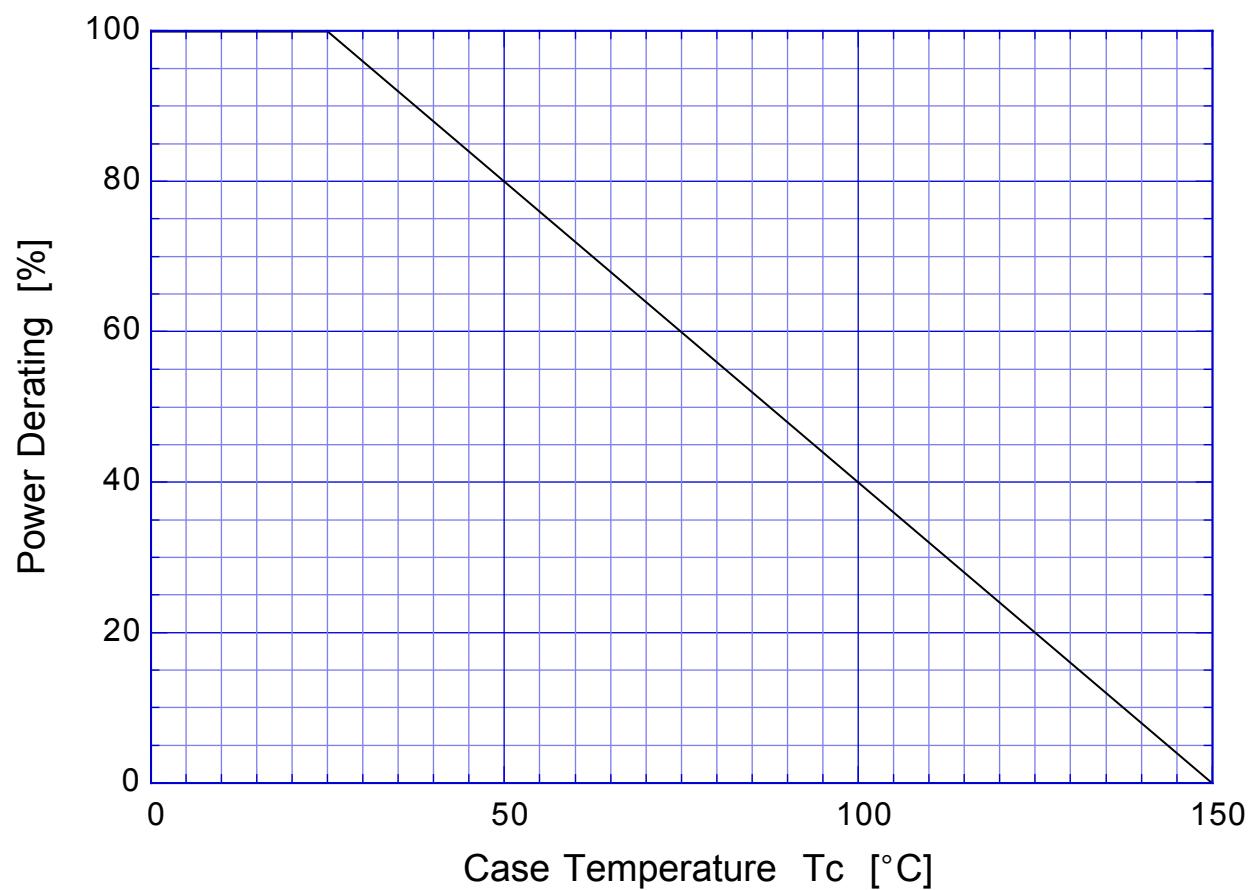


2SK2670 Single Avalanche Current - Inductive Load



2SK2670

Power Derating



2SK2670

Gate Charge Characteristics

